

Researchers develop entangled photon pairs in integrated silicon carbide for first time

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Illustration of entangled photon pair generation within an integrated SiC platform. A classical pump laser undergoes a conversion process within a microring resonator, resulting in the production of two entangled photons. This breakthrough holds great promise for enabling the scalable implementation of quantum information processing on SiC. Credit: *Light: Science & Applications* (2024). DOI: 10.1038/s41377-024-01443-z

Quantum information science is truly fascinating—pairs of tiny particles can be entangled such that an operation on either one will affect them



both even if they are physically separated. A seemingly magical process called teleportation can share information between different far-flung quantum systems.

These different systems can be coupled using quantum processes to form quantum communication networks. Secure communications, distributed quantum computing and quantum sensing are just some of the remarkable potential applications.

Through more than three decades of Quantum 2.0—the period of quantum R&D that covers the development of quantum devices, systems and protocols to generate and use <u>quantum entanglement</u>—the vast majority of experiments required bulky optics and specialized alignment schemes often spanning large special purpose optical tables that are pneumatically floating in order to avoid the minutest of mechanical vibrations.

In much the same way as miniaturized silicon integrated electronics enabled the evolution of computer processors from large room scale assemblies of capacitors, tubes and magnets to tiny but powerful microchips containing millions and millions of components upon which our modern and "smart" technologies are based; quantum components and processes need to be miniaturized using integrated optics to pave the way for large scale deployment and use of <u>quantum information science</u> beyond lab scale experiments and toward real-life uses.

Silicon carbide (SiC) is a leading platform for integrated processes—powered on in recent years by its use in the integrated electronic systems of green technologies such as electrical vehicles. This application has led to significant improvements in the quality of SiC wafers, the base format for creating integrated devices.

In the realm of quantum science, SiC has emerged as a promising



material for Integrated Quantum Photonics (IQP), overcoming scalability issues seen in other materials like silicon. SiC's unique properties make it ideal for integrated quantum optical processes, yet challenges persist in harnessing its full potential. Recent breakthroughs in generating entangled photons on SiC microchips mark a significant step toward unlocking its capabilities for practical quantum applications.

In a <u>new paper</u> published in *Light: Science & Applications*, scientists at the National Institute of Standards and Technology (NIST) in Gaithersburg, MD and at the Carnegie Mellon University of Pittsburg, PA have reported the first demonstration of a chip-scale entangled <u>photon</u> source in SiC.

The device is implemented by a high-order non-linear process known as spontaneous four-wave mixing (SFWM) using an integrated optical microring resonator patterned onto a 4H-SiC-on-insulator platform.

The experiment is designed so that the pairs of photons (signal and idler) are at the telecom wavelength and ideal for being transmitted in optical fibers (which is important for quantum communications and quantum networking) and are created in such a way as to be entangled in time and energy (known as time-energy entanglement). The researchers report generating high-quality and high-purity entangled photon pairs.

These researchers summarize the features of the new device, stating "Our results, including a maximum coincidence-to-accidental ratio > 600 for an on-chip photon pair rate of $(9 \pm 1) \times 10^3$ pairs/s and pump power of 0.17 mW, a heralded ????⁽²⁾ (0) on the order of 10^{-3} , and visibility of a two-photon interference fringe exceeding 99% unequivocally demonstrate that integrated SiC-based devices can be viable for chipscale quantum information processing. In addition, these results are comparable to those obtained from more mature integrated photonic platforms such as silicon."



"We believe that our study lends strong support to the competitiveness of the 4H-SiC-on-insulator platform for quantum applications. For example, the demonstrated entangled photon source can be readily deployed in a fiber-optic network for quantum communication.

"In addition, by aligning the wavelength of the idler photon to the zerophonon line of various color centers found in SiC, we can create entanglement between the signal photon and the spin state. This wavelength alignment process can also be integrated and implemented either through chip-scale dispersion engineering or frequency conversion," they added.

The future for SiC-based integrated optics is certainly promising as the researchers state that "all of these possibilities point to a bright future for SiC-based quantum photonics by enabling the integration of a multitude of chip-scale quantum photonic and electrical processes with color centers for various applications."

More information: Anouar Rahmouni et al, Entangled photon pair generation in an integrated SiC platform, *Light: Science & Applications* (2024). DOI: 10.1038/s41377-024-01443-z

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